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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN THE MATTER OF THE **NEW PCT NATIONAL PHASE PATENT APPLICATION**

OF: Seiji NAKAHATA et al.

USPS EXPRESS MAIL

USSN: TO BE ASSIGNED - new

EV 511 024 341 US

FILED: May 18, 2005

MAY 18 2005

FOR: Method of Processing Surface of Nitride  
Semiconductor Crystal and Nitride  
Semiconductor Crystal Obtained with  
the Method

INTERNATIONAL SERIAL NO.: PCT/JP2004/008090

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COMMISSIONER FOR PATENTS

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ALEXANDRIA, VA 22313-1450

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PRELIMINARY AMENDMENT

Dear Sir:

Please amend the above identified patent application as follows.

**[AMENDMENT FOLLOWS ON NEXT PAGE]**